VS-E5TH1506THN3

Vishay Semiconductors

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Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | | | | |
|--|-------------|--|--|--|--|--|--|--|
| I _{F(AV)} | 15 A | | | | | | | |
| V _R | 600 V | | | | | | | |
| V _F at I _F at 125 °C | 1.15 V | | | | | | | |
| t _{rr} (typ.) | 22 ns | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Package | TO-220AC 2L | | | | | | | |
| Circuit configuration | Single | | | | | | | |

FEATURES

- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-220AC 2L Molding compound meets UL 94 V-0 flammability rating

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|--|-----------------------------------|---|-------------|-------|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | | |
| Repetitive peak reverse voltage | V _{RRM} | | 600 | V | | | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 136 °C, D = 0.50 | 15 | | | | | | |
| Repetitive peak forward current | I _{FRM} | T _C = 136 °C, D = 0.50, f = 20 kHz | 30 | А | | | | | |
| Non-repetitive peak surge current | I _{FSM} | T_{C} = 25 °C, t_{p} = 10 ms, sine wave | 200 | | | | | | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C | | | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|--|-------------------------------------|--|------|-------|-----|-----|--|--|--|
| PARAMETER | MIN. | TYP. | MAX. | UNITS | | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 600 | - | - | | | | |
| Forward voltage | V _F | I _F = 15 A | - | 1.3 | 1.6 | 6 V | | | |
| | | I _F = 15 A, T _J = 125 °C | - | 1.15 | - | | | | |
| Reverse leakage current | I _R | $V_{\rm R} = V_{\rm R}$ rated | - | - | 10 | | | | |
| neverse leakage current | | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated} - 5000$ | | 500 | μA | | | | |
| Junction capacitance | CT | V _R = 200 V | - | 25 | - | pF | | | |
| Series inductance | Ls | Measured to lead 5 mm from package body | - | 8 | - | nH | | | |



COMPLIANT



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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | | | |
|---|------------------|--|--|------|------|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| | | I _F = 1.0 A,dI _F /dt = | $I_F = 1.0 \text{ A,d}I_F/\text{dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | | - | | | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 31 | - | ns | | | |
| | | T _J = 125 °C | | - | 43 | - | | | | |
| Peak recovery current | | T _J = 25 °C | I _F = 10 A dI _F /dt = 1000 A/µs | - | 15 | - | A | | | |
| | I _{RRM} | T _J = 125 °C | $V_{\rm R} = 400 \text{ V}$ | - | 22 | - | | | | |
| Poweree receivery charge | 0 | T _J = 25 °C | | - | 255 | - | nC | | | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 622 | - | | | | |
| Deverse receiver time | + | T _J = 25 °C | | - | 38 | - | ns | | | |
| Reverse recovery time | t _{rr} | T _J = 125 °C | | - | 49 | - | | | | |
| Deals receiver a current | | T _J = 25 °C | I _F = 15 A dI _F /dt = 1000 A/µs | - | 16 | - | A | | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | $V_{\rm B} = 400 \text{ V}$ | - | 24 | - | | | | |
| Devenue and evenue also and | 0 | T _J = 25 °C | | - | 316 | - | nC | | | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 782 | - | nc | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | | |
|--|-----------------------------------|------------------------|------------|------|------------|------------------------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 1.72 | °C/W | | | | |
| Weight | | | - | 2.0 | - | g | | | | |
| weight | | | - | 0.07 | - | oz. | | | | |
| Mounting torque | | | 6.0 (5) | - | 12 (10) | kgf · cm (lbf · in) | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | | | | |
| Marking device | | Case style 2L TO-220AC | E5TH1506TH | | | | | | | |



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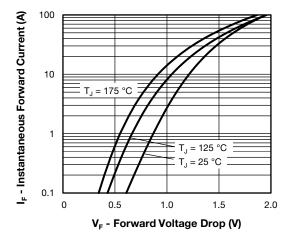


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

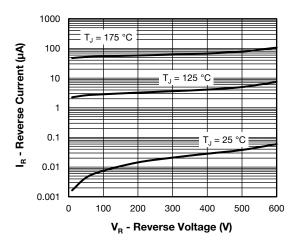
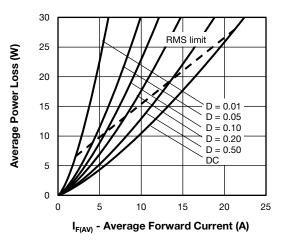
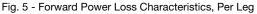


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg





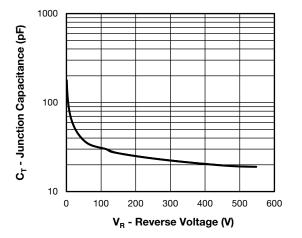


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

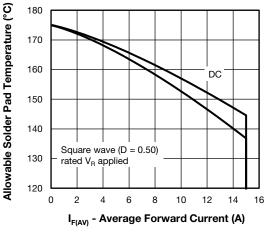


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

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VS-E5TH1506THN3 www.vishay.com **Vishay Semiconductors** 10 Z_{thJC} - Thermal Impedance Junction to Case (°C/W) 1 0.50 0.1 0.20 # 0.10 0.05 DC 0.02 0.01 0.01 0.00001 0.0001 0.001 0.01 0.1 t₁ - Rectangular Pulse Duration (s)

Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

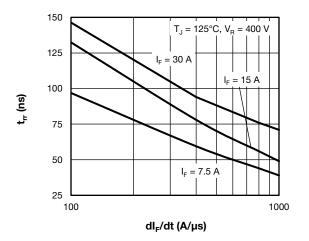


Fig. 7 - Typical Reverse Recovery Time vs. $dI_{\mbox{\scriptsize F}}/dt,$ Per Leg

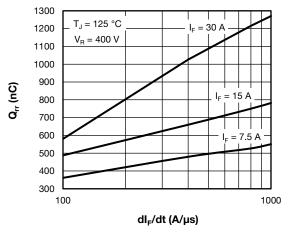


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

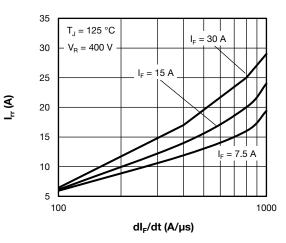


Fig. 9 - Typical Reverse Recovery Current vs. $dI_{\mbox{\rm F}}/dt,$ Per Leg

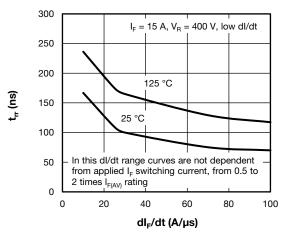


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt , Per Leg

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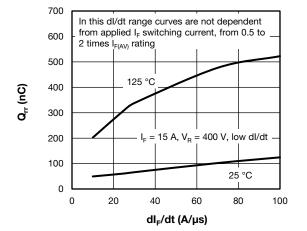
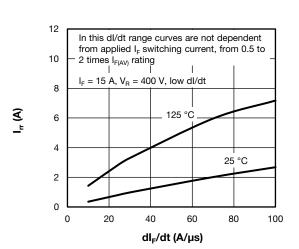


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg



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Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

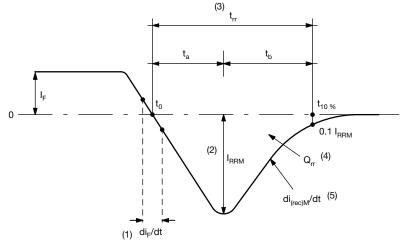


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

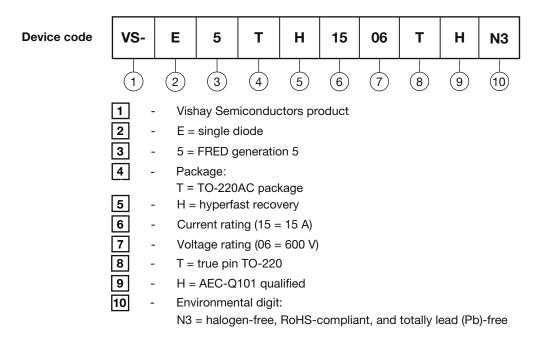


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ORDERING INFORMATION TABLE

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| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-E5TH1506THN3 | 50 | 1000 | Antistatic plastic tube | | | | | |

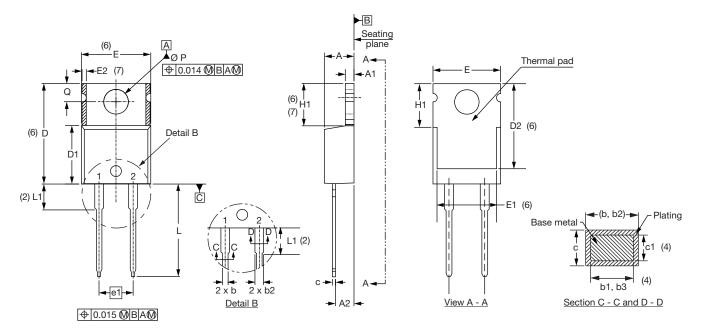
| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--------------------------|
| Dimensions | www.vishay.com/doc?96069 |
| Part marking information | www.vishay.com/doc?95391 |



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2L TO-220AC

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INC | HES | NOTES | | SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|-------------|-------|-------|-------|-------|-------|----------|--------|--------|-------|-------|-------|
| STNIDUL | MIN. | MAX. | MIN. | MAX. | NOTES | NOTES | STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | | E2 | - | 0.76 | - | 0.030 | 7 |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | | H1 | 5.84 | 6.86 | 0.230 | 0.270 | 6, 7 |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | ØР | 3.54 | 3.73 | 0.139 | 0.147 | |
| с | 0.36 | 0.61 | 0.014 | 0.024 | | | Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | | | | | | | |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 | | | | | | | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | | | | | | | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 | | | | | | | |
| E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 | | | | | | | |

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

- $^{\left(7\right)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC[®] TO-220, except D2, where JEDEC[®] minimum is 0.480"

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